SPECIFICATION

(300A/1700V-IGBT Module)

Device Name

IGBT Module (RoHS compliant product)

Type Name

2MBI300VH-170-50

Spec. No.

MS5F7930

	DATE	NAME	APPROVAL
DRAWN	Dec15-11	S. Horie	
CHECKED	Dec15-11	S. Hiyashita	D. The
			O. Ilawa

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DWG.No. MS5F7930

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Revised Records

Date	Classification	Ind.	Content	Applied date	Drawn	Checked	Checked	Approved
Đec,-15-11	enactment	-	-	Issued date	-	S _i Miyasluta	M.Kosafa	0.Ikawa
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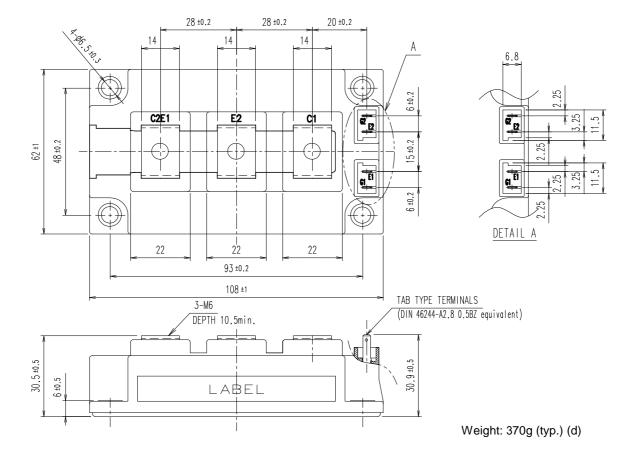
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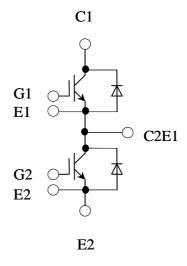
Type Name: 2MBI300VH-170-50 (RoHS compliant products)

1. Outline Drawing (Unit : mm)



2. Equivalent Circuit

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DWG No.

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3. Absolute Maximum Ratings (at Tc= 25°C unless otherwise specified)

	Items		Cond	itions	Maximum Ratings	Units
Collector-	Emitter voltage	VCES			1700	V
Gate-Emit	ter voltage	VGES			±20	V
		Ic	Continuous	Tc=100°C	300	
		IC	Continuous	Tc=25°C	440	
Collector	current	lc pulse	1ms		600	
		-lc			300	
		-lc pulse	1ms		600	
Collector	power dissipation	Pc	1 device		1805	W
Junction to	emperature	Tj			175	
	junction temperature	Tjop			150	
(under sw	itching conditions)	ПОР			100	°C
Case tem	perature	Tc			125	
Storage temperature		Tstg			-40 ~ 125	
Isolation	between terminal and copper base (*1)		AC: 1min.		4000	VAC
voltage	,	Viso	7.0. 1111111.		1000	٠,١٥
Screw	Mounting (*2)	-			6.0	Nm
Torque	Terminals (*3)	-		·	5.0	14 111

All terminals should be connected together during the test.

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Recommendable Value: 3.0-6.0 Nm (M5 or M6) Recommendable Value: 2.5-5.0 Nm (M6)

^(*1) (*2) (*3)

4. Electrical characteristics (at Tj= 25°C unless otherwise specified)

NOTICE:

The external gate resistance (Rg) shown below is one of our recommend value for the purpose of minimum switching loss. However the optimum Rg depends on circuit configuration and/or environment. We recommend that the Rg has to be carefully chosen based on consideration if IGBT module matches design criteria, for example, switching loss, EMC/EMI, spike voltage, surge current and no unexpected oscillation and so on.

Items	Symbols	Condition	26	Ch	aracteris	tics	Units	
items	Symbols	Condition	15	min.	typ.	max.	Units	
Zero gate voltage Collector current	ICES	VGE=0V, VCE=1700	V	-	-	2.0	mA	
Gate-Emitter leakage current	IGES	VCE=0V, VGE=±20\	/	-	-	400	nA	
Gate-Emitter threshold voltage	VGE(th)	VCE=20V, Ic=300m/		6.0	6.5	7.0	V	
	VCE(sat)		Tj=25°C	ı	2.15	2.60		
	(terminal)	VGE=15V, Ic=300A	Tj=125°C		2.55	-		
Collector-Emitter			Tj=150°C		2.60		V	
saturation voltage	VCE(sat)		Tj=25°C	-	2.00	2.45		
	(chip)	VGE=15V, Ic=300A	Tj=125°C	-	2.40	-	<u> </u>	
			Tj=150°C		2.45			
Internal gate resistance	Rg(int)	-		-	2.5	-		
Input capacitance	Cies	VCE=10V, VGE=0V,	f=1MHz	-	33	-	nF	
	ton			ı	950	-		
Turn-on time	tr	Vcc=900V, Ic=300A,	\/GE_±15\/	-	350	-		
	tr(i)	Rg=2.4Ω, Tj=150°C,	· ·	-	60	-	nsec	
Turn-off time	toff	$R_{g=2.4\Omega}$, $r_{j=150}$ C,	LS=30IIII	-	1050	-		
rum-on time	tf			-	140	-		
	VF		Tj=25°C	-	1.95	2.40		
	(terminal)	VGE=0V, IF=300A	Tj=125°C	-	2.15	-		
Forward on voltage			Tj=150°C		2.15		V	
Forward on voltage	VF		Tj=25°C	-	1.80	2.25		
	(chip)	VGE=0V, IF=300A	Tj=125°C	-	2.05	-		
			Tj=150°C		2.05			
Reverse recovery time	trr	IF=300A		-	220	-	nsec	

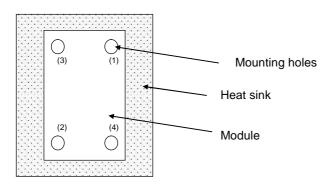
5. Thermal resistance characteristics

Items	Symbols	Conditions	Characteristics			Units
items	Symbols Conditions		min.	typ.	max.	Ullits
Thermal resistance(1device)	Dth/i o)	IGBT	-	-	0.083	
Thermal resistance (Tuevice)	Rth(j-c)	FWD	-	-	0.130	°C/W
Contact thermal resistance (1device) (*1)	Rth(c-f)	with Thermal Compound	-	0.0125	-	C/VV

^(*1) This is the value which is defined mounting on the additional cooling fin with thermal compound.

6. Recommend way of module mounting on Heat sink

- (1) Initial: 1/3 specified torque, sequence (1) (2) (3) (4)
- (2) Final Full specified torque (3.0 6.0 Nm), sequence(4) (3) (2) (1)



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DWG No.

MS5F7930

7. Indication on module

Display on the module label

- Logo of production
- Type name : 2MBI300VH-170-50 - IC, VCES rating : 300A 1700V
- Lot No. (5 digits)
- Place of manufacturing (code)
- Bar code

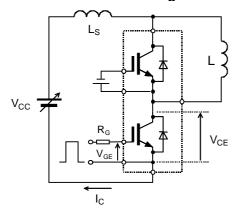
8. Applicable Category

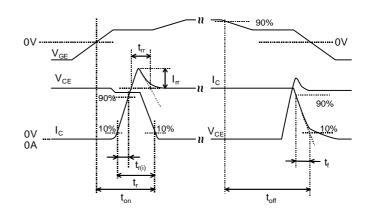
This specification is applied to IGBT Module named 2MBI300VH-170-50.

9. Storage and transportation notes (保管・運搬上の注意事項)

- ・ The module should be stored at a standard temperature of 5 to 35°C and humidity of 45 to 75%. 常温・常湿保存が望ましい。(5~35°C, 45~75%)
- Store modules in a place with few temperature changes in order to avoid condensation on the module surface. 急激な温度変化のなきこと。(モジュール表面が結露しないこと)
- ・ Avoid exposure to corrosive gases and dust. 腐食性ガスの発生場所、塵埃の多い場所は避けること。
- Avoid excessive external force on the module.
 製品に荷重がかからないように十分注意すること。
- Store modules with unprocessed terminals.
 モジュールの端子は未加工の状態で保管すること。
- Do not drop or otherwise shock the modules when transporting.
 製品の運搬時に衝撃を与えたり、落下させたりしないこと。
- Do not pull the springs when transporting and handling.
 製品の運搬時や取り扱い時にスプリングを引っ張らないこと。

10. Definitions of switching time





11. Packing and labeling

Display on the packing box

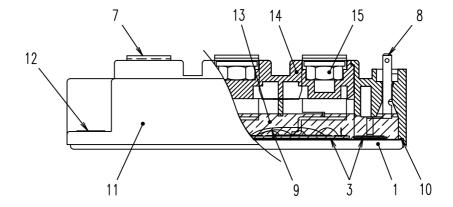
- Logo of production
- Type name
- Lot No
- Products quantity in a packing box

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MS5F7930

12. List of materials (材料リスト)



No.	Parts	Material (main)	Ref.
1	Base Plate	Cu	Ni plating
2	Solder (Under Isolation substrate)	Sn / Sb	(Not drawn in above)
3	Isolation substrate	$Al_2O_3 + Cu$	
4	Solder (Under chip / Under terminal)	Sn / Ag base	(Not drawn in above)
5	IGBT chip	Silicon	(Not drawn in above)
6	FWD chip	Silicon	(Not drawn in above)
7	Main terminal	Cu	Ni plating or Sn plating
8	Sub terminal	Cu or Brass	Ni plating or Sn plating
9	Wiring	Aluminum	
10	Adhesive	Silicone resin	
11	Case	PPS resin	UL 94V-0
12	Ring	Fe	Trivalent Chromate treatment
13	Silicone Gel	Silicone resin	
14	Nut Glove	PPS resin	UL 94V-0
15	Nut	Fe	Trivalent Chromate treatment
16	Label	PET	(Not drawn in above)

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DWG No.

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13. Reliability test Items

Reliability Test Items

Test					Reference norms	Number	Accept-
cate-		Test items	Test metho	ds and conditions	EIAJ ED-4701	of	ance
gories					(Aug2001 edition)	sample	number
	1	Terminal Strength	Pull force : 2	20N (Controle terminal)	Test Method 401 method	5	(0:1)
		(Pull test)	Test time : 1	0±1 sec.			
	2	Mounting Strength	Screw torque	: 3.0 ~ 6.0 N·m (M5 or M6	Test Method 402	5	(0:1)
ţţ				:	method		
Mechanical Tests			Test time	: 10±1 sec.			
<u> </u>	3	Vibration	Range of frequency	: 10 ~ 500Hz	Test Method 403	5	(0:1)
jč			Sweeping time	: 15 min.	Reference 1		
Jar			Acceleration	: 100m/s ²	Condition code B		
ecl			Sweeping direction	: Each X,Y,Z axis			
≥				: 6 hr. (2hr./direction)			
	4	Shock	Maximum accelerati		Test Method 404	5	(0:1)
			Pulse width	: 1.0msec.	Condition code B		
			Direction	: Each X,Y,Z axis			
			Test time	: 3 times/direction			
	1	High Temperature		: 125 ± 5 °C	Test Method 201	5	(0:1)
		Storage		: 1000hr.			
	2	Low Temperature		: -40 ± 5 °C	Test Method 202	5	(0:1)
		Storage	Test duration	: 1000hr.			
	3	Temperature	Storage temp.	: 85 ± 2 °C	Test Method 103	5	(0:1)
		Humidity	Relative humidity	: 85 ± 5%	Test code C		
		Storage	Test duration	: 1000hr.			
Ś	4	Unsaturated	Test temp.	: 120 ± 2 °C	Test Method 103	5	(0:1)
est		Pressurized	Test humidity	: 85 ± 5%	Test code E		
Environment Tests		Vapor	Test duration	: 96hr.		_	
- tu	5	Temperature		Low temp40 ± 5 °C	Test Method 105	5	(0:1)
Ĕ		Cycle	Test temp.	: High temp. 125 ± 5 °C			
o				RT 5~35°C			
έ			Dwell time	: High ~ RT ~ Low ~ RT			
ᇤ			l	1hr. 0.5hr. 1hr. 0.5hr.			
	_		Number of cycles	: 100 cycles	T (M () 1007	_	(0.4)
	6	Thermal Shock	Test temp.	: High temp. 100 ⁺⁰ ₋₅ °C	Test Method 307	5	(0:1)
				Material de la const	method		
			Used liquid	: Water with ice and	Condition code B		
			Dinaina tias s	boiling water			
			Dipping time	: 5 min. par each temp.			
			Transfer time	: 10 sec.			
			Number of cycles	: 10 cycles			

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Test items	Test me	ethods and conditions	Reference norms EIAJ ED-4701 (Aug2001 edition)	Number of sample	Accept- ance number
1 High temperature Reverse Bias (for Collector -	Test temp.	: Tj = 150 (-0 /+5)	Test Method 101	5	(0:1)
Emitter)	Bias Method	: Applied DC voltage to C-E VGE = 0V			
2 High temperature Bias (for gate)			Test Method 101	5	(0:1)
	Test duration	: 1000hr.			
3 Temperature Humidity Bias	Bias Voltage	: VC = 0.8×VCES	Test Method 102 Condition code C	5	(0:1)
4 Intermitted	Test duration	: 1000hr.	Toot Mothod 106	-	(0:1)
Operating Life (Power cycle) (for IGBT)	OFF time Test temp.	: 18 sec. : 100±5 deg Tj 150 , Ta=25±5	rest Method 106	5	(0:1)
	1 High temperature Reverse Bias (for Collector - Emitter) 2 High temperature Bias (for gate) 3 Temperature Humidity Bias 4 Intermitted Operating Life (Power cycle)	1 High temperature Reverse Bias (for Collector - Emitter) Bias Voltage Bias Method Test duration 2 High temperature Bias (for gate) Test temp. Bias Voltage Bias Method Test duration 3 Temperature Humidity Bias Test temp. Relative humidit Bias Voltage Bias Method Test duration 4 Intermitted Operating Life (Power cycle) ON time OFF time Test temp.	High temperature Reverse Bias Test temp. Tj = 150 (-0 /+5) (for Collector - Emitter) Bias Voltage VC = 0.8×VCES Bias Method Applied DC voltage to C-E VGE = 0V Test duration Test temp. Tj = 150 (-0 /+5)	Test items	Test items

Failure Criteria

Item	Item Characteristic		Symbol	Failure crite	eria	Unit	Note
item			Symbol	Lower limit	Upper limit		
Electrical	Leakage current	i	ICES	•	USL×2	mΑ	
characteristic			±IGES	ī	USL×2	μΑ	
	Gate threshold v	/oltage	VGE(th)	LSL×0.8	USL×1.2	mΑ	
	Saturation voltage	ge	VCE(sat)	-	USL×1.2	V	
	Forward voltage		VF	-	USL×1.2	V	
	Thermal	IGBT	Δ VGE		USL×1.2	mV	
	resistance		or ∆ VCE	-	USLX1.2		
		FWD	ΔVF	-	USL×1.2	mV	
	Isolation voltage)	Viso	Broken insulation		-	
Visual	Visual inspection	n					
inspection	Peeling Plating and the othe	rs	-	The visual sample		-	

LSL : Lower specified limit.

Note : USL : Upper specified limit.

Each parameter measurement read-outs shall be made after stabilizing the components at room ambient for 2 hours minimum, 24 hours maximum after removal from the tests. And in case of the wetting tests, for example, moisture resistance tests, each component shall be made wipe or dry completely before the measurement.

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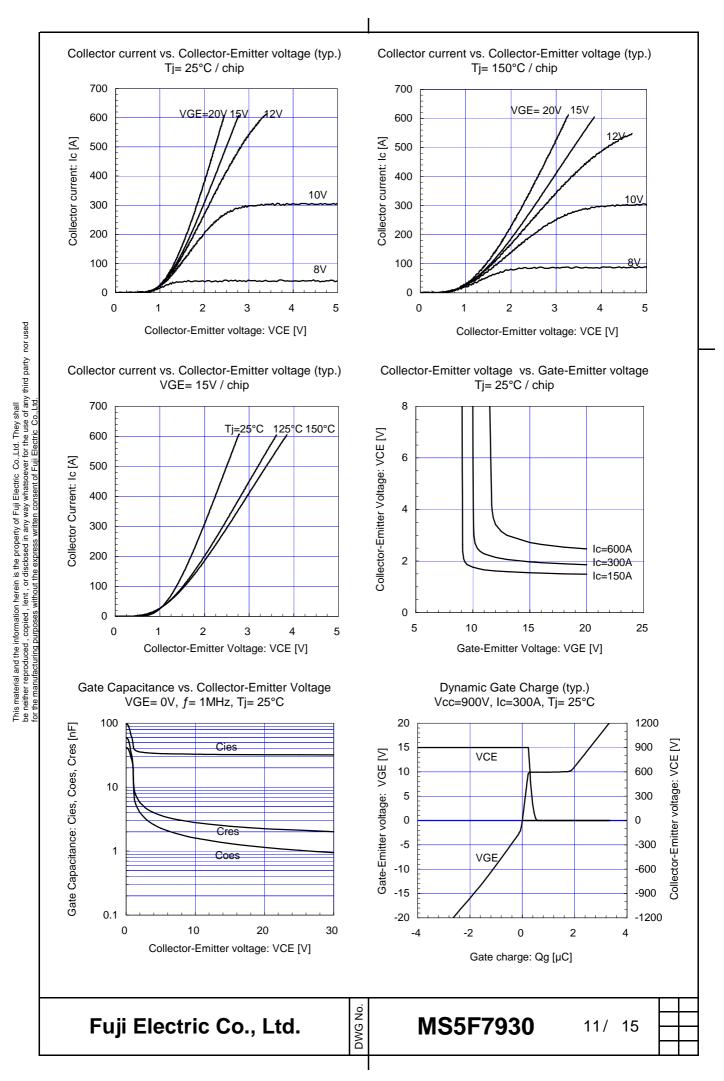
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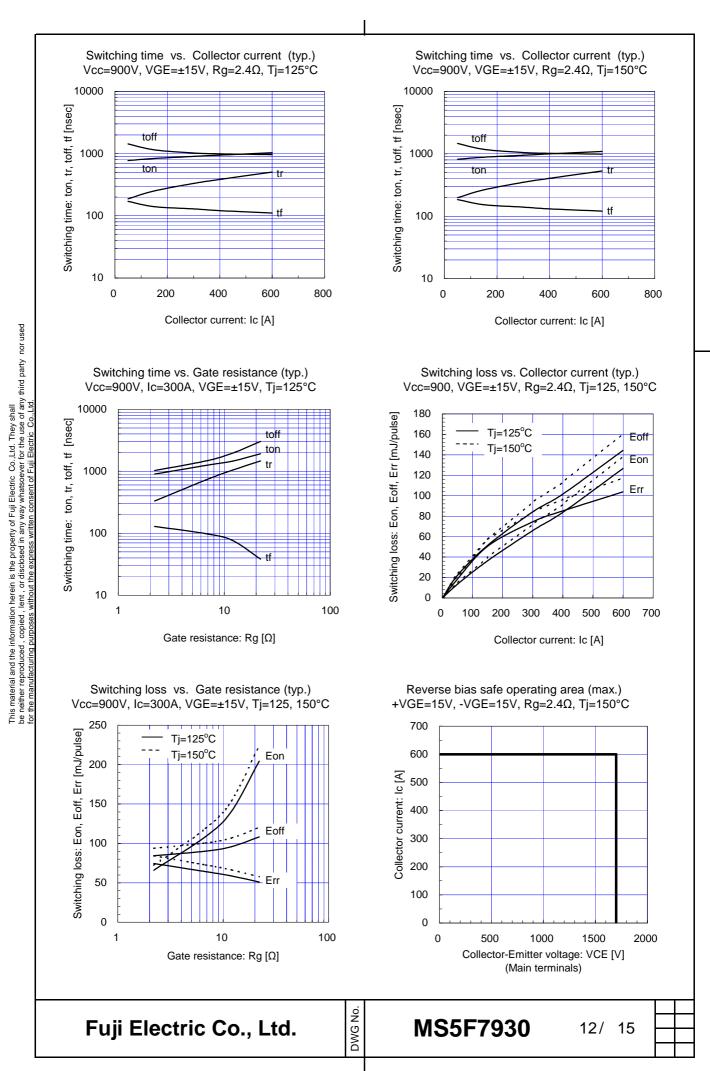
Reliability Test Results

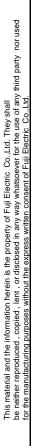
Test			Reference	Number of	Number of
cate-		Test items	norms	test	failure
gories			EIAJ ED-4701	sample	sample
	1	Terminal Strength	Test Method 401	5	0
		(Pull test)	Method		
	2	Mounting Strength	Test Method 402	5	0
sts			method		
Te	3	Vibration	Test Method 403	5	0
Mechanical Tests			Condition code B		
anic	4	Shock	Test Method 404	5	0
ch			Condition code B		
Me	5	Solderabitlity	Test Method 303	5	0
			Condition code A		
	6	Resistance to Soldering Heat	Test Method 302	5	0
			Condition code A		
	1	High Temperature Storage	Test Method 201	5	0
s	2	Low Temperature Storage	Test Method 202	5	0
est	3	Temperature Humidity	Test Method 103	5	0
		Storage	Test code C		
ner	4	Unsaturated	Test Method 103	5	0
onr		Pressurized Vapor	Test code E		
Environment Tests	5	Temperature Cycle	Test Method 105	5	0
	6	Thermal Shock	Test Method 307 method Condition code A	5	0
,	1	High temperature Reverse Bias	Test Method 101	5	0
Endurance Tests	2	High temperature Bias (for gate)	Test Method 101	5	0
ance	3	Temperature Humidity Bias	Test Method 102	5	0
lurs			Condition code C		
End	4	Intermitted Operating Life (Power cycling) (for IGBT)	Test Method 106	5	0

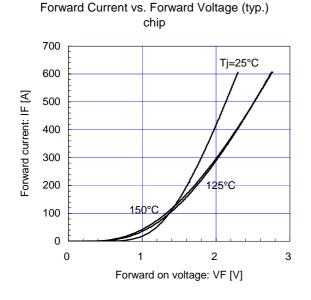
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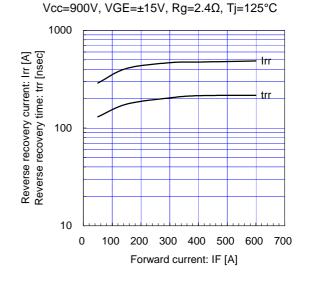
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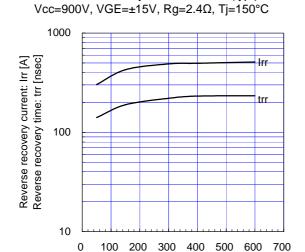






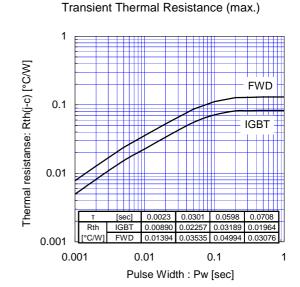


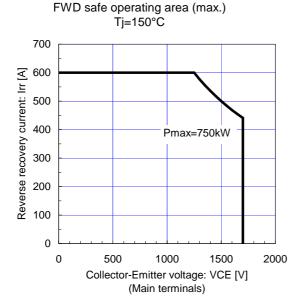
Reverse Recovery Characteristics (typ.)



Forward current: IF [A]

Reverse Recovery Characteristics (typ.)





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DWG No.

MS5F7930

Warnings

- This product shall be used within its maximum rating (voltage, current, and temperature). This product may be broken in case of using beyond the maximum ratings.
 製品の最大定格(電圧,電流,温度等)の範囲内で御使用下さい。最大定格を超えて使用すると、素子が破壊する場合があります。
- Connect adequate fuse or protector of circuit between three-phase line and this product to prevent the
 equipment from causing secondary destruction, such as fire, its spreading, or explosion.
 万一の不慮の事故で素子が破壊した場合を考慮し、商用電源と本製品の間に適切な容量のヒューズ又はプレーカーを必ず付けて火災, 爆発, 延焼等の2次破壊を防いでください。
- Use this product after realizing enough working on environment and considering of product's reliability life.
 This product may be broken before target life of the system in case of using beyond the product's reliability life.
 - 製品の使用環境を十分に把握し、製品の信頼性寿命が満足できるか検討の上、本製品を適用して下さい。製品の 信頼性寿命を超えて使用した場合、装置の目標寿命より前に素子が破壊する場合があります。
- If the product had been used in the environment with acid, organic matter, and corrosive gas (hydrogen sulfide, sulfurous acid gas), the product's performance and appearance can not be ensured easily. 酸・有機物・腐食性ガス(硫化水素, 亜硫酸ガス等)を含む環境下で使用された場合、製品機能・外観等の保証はできません。
- Use this product within the power cycle curve (Technical Rep.No.: MT5F12959). Power cycle capability is classified to delta-Tj mode which is stated as above and delta-Tc mode. Delta-Tc mode is due to rise and down of case temperature (Tc), and depends on cooling design of equipment which use this product. In application which has such frequent rise and down of Tc, well consideration of product life time is necessary. 本製品は、パワーサイクル寿命カープ以下で使用下さい(技術資料No.: MT5F12959)。パワーサイクル耐量にはこのΔTj による場合の他に、ΔTcによる場合があります。これはケース温度(Tc)の上昇下降による熱ストレスであり、本製品をご使用する際の放熱設計に依存します。ケース温度の上昇下降が頻繁に起こる場合は、製品寿命に十分留意してご使用下さい。
- Never add mechanical stress to deform the main or control terminal. The deformed terminal may cause poor contact problem.
 主端子及び制御端子に応力を与えて変形させないで下さい。 端子の変形により、接触不良などを引き起こす場合があります。
- Use this product with keeping the cooling fin's flatness between screw holes within 50µm at 100mm and the roughness within 10µm. Also keep the tightening torque within the limits of this specification. Too large convex of cooling fin may cause isolation breakdown and this may lead to a critical accident. On the other hand, too large concave of cooling fin makes gap between this product and the fin bigger, then, thermal conductivity will be worse and over heat destruction may occur. 冷却フィンはネジ取り付け位置間で平坦度を100mmで50µm以下、表面の粗さは10µm以下にして下さい。過大な凸反りがあったりすると本製品が絶縁破壊を起こし、重大事故に発展する場合があります。また、過大な凹反りやゆがみ等があると、本製品と冷却フィンの間に空隙が生じて放熱が悪くなり、熱破壊に繋がることがあります。
- In case of mounting this product on cooling fin, use thermal compound to secure thermal conductivity. If the thermal compound amount was not enough or its applying method was not suitable, its spreading will not be enough, then, thermal conductivity will be worse and thermal run away destruction may occur. Confirm spreading state of the thermal compound when its applying to this product. (Spreading state of the thermal compound can be confirmed by removing this product after mounting.) 素子を冷却フィンに取り付ける際には、熱伝導を確保するためのコンパウンド等をご使用ください。又、塗布量が不足したり、塗布方法が不適だったりすると、コンパウンドが十分に素子全体に広がらず、放熱悪化による熱破壊に繋がる事があります。
 - コンパウンドを塗布する際には、製品全面にコンパウンドが広がっている事を確認して〈ださい。 (実装した後に素子を取りはずすとコンパウンドの広がり具合を確認する事が出来ます。)
- It shall be confirmed that IGBT's operating locus of the turn-off voltage and current are within the RBSOA specification. This product may be broken if the locus is out of the RBSOA.
 ターンオフ電圧・電流の動作軌跡がRBSOA仕様内にあることを確認して下さい。RBSOAの範囲を超えて使用すると素子が破壊する可能性があります。

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Warnings

- If excessive static electricity is applied to the control terminals, the devices may be broken. Implement some countermeasures against static electricity.
 制御端子に過大な静電気が印加された場合、素子が破壊する場合があります。取り扱い時は静電気対策を実施して下さい。
- Never add the excessive mechanical stress to the main or control terminals when the product is applied to
 equipments. The module structure may be broken.
 素子を装置に実装する際に、主端子や制御端子に過大な応力を与えないで下さい。端子構造が破壊する可能性があります。
- In case of insufficient -VGE, erroneous turn-on of IGBT may occur. -VGE shall be set enough value to prevent this malfunction. (Recommended value: -VGE = -15V)
 逆バイアスゲート電圧-VGEが不足しますと誤点弧を起こす可能性があります。誤点弧を起こさない為に-VGEは 十分な値で設定して下さい。(推奨値:-VGE = -15V)
- In case of higher turn-on dv/dt of IGBT, erroneous turn-on of opposite arm IGBT may occur. Use this product in the most suitable drive conditions, such as +VGE, -VGE, RG, CGE to prevent the malfunction. ターンオン dv/dt が高いと対向アームのIGBTが誤点弧を起こす可能性があります。誤点弧を起こさない為の最適なドライプ条件(+VGE, -VGE, RG, CGE)でご使用下さい。
- This product may be broken by avalanche in case of VCE beyond maximum rating VCES is applied between C-E terminals. Use this product within its maximum voltage.
 VCESを超えた電圧が印加された場合、アバランシェを起こして素子破壊する場合があります。VCEは必ず最大定格の範囲内でご使用下さい。
- Use the same lot product only for parallel connection.
 If different lot product is used for parallel connection without confirmation of Fuji Electric Co.Ltd., the product performance cannot be ensured.
 この製品をパラレル接続する場合は、同一ロットのものを使用してください。
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Cautions

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If there is any unclear matter in this specification, please contact Fuji Electric Co., Ltd.

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